

Maria Kamińska

List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/7965710/publications.pdf>

Version: 2024-02-01

34
papers

566
citations

687220

13
h-index

642610

23
g-index

35
all docs

35
docs citations

35
times ranked

765
citing authors

#	ARTICLE	IF	CITATIONS
1	Mono- and Di-Pyrene [60]Fullerene and [70]Fullerene Derivatives as Potential Components for Photovoltaic Devices. <i>Molecules</i> , 2021, 26, 1561.	1.7	10
2	Investigation of polyaniline doped with camphorsulfonic acid in chloroform solution as a hole transporting layer in PTB7: PCBM and perovskite-based solar cells. <i>Electrochimica Acta</i> , 2021, 380, 138264.	2.6	14
3	Properties of graphene deposited on GaN nanowires: influence of nanowire roughness, self-induced nanogating and defects. <i>Beilstein Journal of Nanotechnology</i> , 2021, 12, 566-577.	1.5	3
4	The effects of doping and coating on degradation kinetics in perovskites. <i>Solar Energy Materials and Solar Cells</i> , 2021, 230, 111142.	3.0	8
5	Highly effective gating of graphene on GaN. <i>Applied Surface Science</i> , 2021, 560, 149939.	3.1	3
6	Electrochemical and optical studies of new symmetrical and unsymmetrical imines with thiazole and thiophene moieties. <i>Electrochimica Acta</i> , 2020, 332, 135476.	2.6	15
7	A comprehensive optical and electrical study of unsymmetrical imine with four thiophene rings and their binary and ternary compositions with PTB7 and PC70BM towards organic photovoltaics. <i>RSC Advances</i> , 2020, 10, 44958-44972.	1.7	9
8	Surface-enhanced Raman scattering in graphene deposited on Al Ga ^{1-α} N/GaN axial heterostructure nanowires. <i>Applied Surface Science</i> , 2019, 475, 559-564.	3.1	7
9	Radiative recombination and other processes related to excess charge carriers, decisive for efficient performance of electronic devices. <i>Lithuanian Journal of Physics</i> , 2018, 58, .	0.1	5
10	Towards designing polymers for photovoltaic applications: A DFT and experimental study of polyazomethines with various chemical structures. <i>Spectrochimica Acta - Part A: Molecular and Biomolecular Spectroscopy</i> , 2017, 181, 208-217.	2.0	12
11	High-spin configuration of Mn in Bi ₂ Se ₃ three-dimensional topological insulator. <i>Journal of Magnetism and Magnetic Materials</i> , 2016, 419, 301-308.	1.0	8
12	Toward Better Efficiency of Air-Stable Polyazomethine-Based Organic Solar Cells Using Time-Resolved Photoluminescence and Light-Induced Electron Spin Resonance as Verification Methods. <i>Journal of Physical Chemistry C</i> , 2016, 120, 11415-11425.	1.5	24
13	Enhanced Raman scattering and weak localization in graphene deposited on GaN nanowires. <i>Physical Review B</i> , 2015, 92, .	1.1	9
14	New environmentally friendly polyazomethines with thiophene rings for polymer solar cells. <i>Solar Energy</i> , 2015, 117, 246-259.	2.9	51
15	Electron scattering in graphene with adsorbed NaCl nanoparticles. <i>Journal of Applied Physics</i> , 2015, 117, 014308.	1.1	3
16	How do 10-camphorsulfonic acid, silver or aluminum nanoparticles influence optical, electrochemical, electrochromic and photovoltaic properties of air and thermally stable triphenylamine-based polyazomethine with carbazole moieties?. <i>Electrochimica Acta</i> , 2015, 185, 198-210.	2.6	24
17	Li ₄ Ti ₅ O ₁₂ modified with Ag nanoparticles as an advanced anode material in lithium-ion batteries. <i>Journal of Power Sources</i> , 2014, 245, 764-771.	4.0	89
18	Novel graphene oxide/manganese oxide nanocomposites. <i>RSC Advances</i> , 2013, 3, 22857.	1.7	18

#	ARTICLE	IF	CITATIONS
19	Investigation of optical and electrical properties of new aromatic polyazomethine with thiophene and cardo moieties toward application in organic solar cells. <i>Synthetic Metals</i> , 2013, 185-186, 17-24.	2.1	32
20	Microwave studies of weak localization and antilocalization in epitaxial graphene. , 2013, , .		1
21	Enhancement of elastic and inelastic scattering lengths in quasi-free-standing graphene measured with contactless microwave spectroscopy. <i>Physical Review B</i> , 2013, 88, .	1.1	9
22	Contactless microwave studies of weak localization in epitaxial graphene. <i>Physical Review B</i> , 2012, 86, .	1.1	10
23	Raman measurements of temperature dependencies of phonons in LiMnPO ₄ . <i>Materials Chemistry and Physics</i> , 2011, 127, 391-396.	2.0	25
24	Structural and magnetic properties of the molecular beam epitaxy grown MnSb layers on GaAs substrates. <i>Journal of Applied Physics</i> , 2009, 106, .	1.1	9
25	Mn configuration in III-V semiconductors and its influence on electric transport and semiconductor magnetism. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2009, 6, 2769-2777.	0.8	11
26	Structural and magnetic properties of MnAs/GaAs ferromagnetic semiconductor nanocomposite material. <i>Journal of Materials Science: Materials in Electronics</i> , 2008, 19, 740-743.	1.1	1
27	Mn and other magnetic impurities in GaN and other III-V semiconductors – perspective for spintronic applications. <i>Journal of Materials Science: Materials in Electronics</i> , 2008, 19, 828-834.	1.1	30
28	Chapter 8 Magnetic Impurities in Wide Bandgap III-V Semiconductors. <i>Semiconductors and Semimetals</i> , 2008, , 325-369.	0.4	9
29	Fabrication and Physical Properties of SiC-GaAs Nano-Composites. <i>Solid State Phenomena</i> , 2006, 114, 297-302.	0.3	1
30	Carbothermally-assisted aerosol synthesis of semiconducting materials in the system GaN/Mn. <i>Journal of Physics and Chemistry of Solids</i> , 2004, 65, 639-645.	1.9	17
31	d exchange interaction in GaN:Mn studied by electron paramagnetic resonance. <i>Applied Physics Letters</i> , 2003, 83, 5428-5430.	1.5	13
32	Influence of Be Doping on Material Properties of Low-Temperature-Grown GaAs. <i>Materials Research Society Symposia Proceedings</i> , 2002, 719, 141.	0.1	0
33	Chapter 2 EL2 Defect in GaAs. <i>Semiconductors and Semimetals</i> , 1993, 38, 59-89.	0.4	38
34	Low Temperature GaAs: Electrical and Optical Properties. <i>Materials Science Forum</i> , 1992, 83-87, 1033-1044.	0.3	48